## **Octal 3-State Noninverting Buffer/Line Driver/Line Receiver**

## High–Performance Silicon–Gate CMOS

The MC74HC541A is identical in pinout to the LS541. The device inputs are compatible with Standard CMOS outputs. External pull-up resistors make them compatible with LSTTL outputs.

The HC541A is an octal noninverting buffer/line driver/line receiver designed to be used with 3-state memory address drivers, clock drivers, and other bus-oriented systems. This device features inputs and outputs on opposite sides of the package and two ANDed active-low output enables.

The HC541A is similar in function to the HC540A, which has inverting outputs.

## Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1 µA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance With the JEDEC Standard No. 7 A Requirements
- Chip Complexity: 134 FETs or 33.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant





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CASE 948E



## MARKING DIAGRAMS

HC541A AWLYYWWG 1 U U U U U U U U U U	
SOIC-20	TSSOP-20
WL, L = YY, Y = WW, W =	Assembly Location Wafer Lot Year Work Week Pb–Free Package
	may be in either location)

(Note: Microdot may be in either location)

## **FUNCTION TABLE**

Inputs OE1 OE2 A		
н	Н	
Х	Z	
Х	Z	
	L H X	

Z = High Impedance

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

## MAXIMUM RATINGS

Symbol	F	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V	
VI	DC Input Voltage		$-0.5 \le V_I \le V_{CC} + 0.5$	V
Vo	DC Output Voltage (Note 1)		$-0.5 \leq V_O \leq V_{CC} + 0.5$	V
Ι <sub>ΙΚ</sub>	DC Input Diode Current		±20	mA
I <sub>OK</sub>	DC Output Diode Current		±35	mA
Ι <sub>Ο</sub>	DC Output Sink Current		±35	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin		±75	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±75	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for	or 10 Seconds	260	°C
TJ	Junction Temperature under Bias		+150	°C
$\theta_{JA}$	Thermal Resistance	SOIC TSSOP	96 128	°C/W
PD	Power Dissipation in Still Air at 85°C SOIC TSSOP		500 450	mW
MSL	Moisture Sensitivity		Level 1	
$F_{R}$	Flammability Rating	Oxygen Index: 30% – 35%	UL 94 V–0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 4000 > 300 > 1000	V
I <sub>Latchup</sub>	Latchup Performance	Above $V_{CC}$ and Below GND at 85°C (Note 5)	±300	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I<sub>O</sub> absolute maximum rating must be observed.

Tested to EIA/JESD22–A114–A.
Tested to EIA/JESD22–A115–A.

4. Tested to JESD22-C101-A.

5. Tested to EIA/JESD78.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Symbol Parameter		Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	(Referenced to GND)	2.0	6.0	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage	(Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range, All Package Types			+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise/Fall Time (Figure 2)	V <sub>CC</sub> = 2.0 V V <sub>CC</sub> = 4.5 V V <sub>CC</sub> = 6.0 V	0 0 0	1000 500 400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

## DC CHARACTERISTICS (Voltages Referenced to GND)

				Gua	ranteed Li	imit	
Symbol	Parameter	Condition	v <sub>cc</sub> v	–55 to 25°C	≤85°C	≤125°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage	V <sub>OUT</sub> = 0.1 V  I <sub>OUT</sub>   ≤ 20 μA	2.0 3.0 4.5 6.0	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	V
V <sub>IL</sub>	Maximum Low-Level Input Voltage	$\label{eq:VOUT} \begin{array}{l} V_{OUT} = V_{CC} - 0.1 \ V \\  I_{OUT}  \leq 20 \ \mu A \end{array}$	2.0 3.0 4.5 6.0	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	V
V <sub>OH</sub>	Minimum High–Level Output Voltage		2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$\label{eq:VIN} \begin{array}{ c c } V_{IN} = V_{IL} &  I_{OUT}  \leq 3.6 \text{ mA} \\  I_{OUT}  \leq 6.0 \text{ mA} \\  I_{OUT}  \leq 7.8 \text{ mA} \end{array}$	3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.20 3.70 5.20	
V <sub>OL</sub>	Maximum Low–Level Output Voltage		2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$\label{eq:VIN} \begin{array}{ c c c } V_{IN} = V_{IH} & &  I_{OUT}  \leq 3.6 \text{ mA} \\  I_{OUT}  \leq 6.0 \text{ mA} \\  I_{OUT}  \leq 7.8 \text{ mA} \end{array}$	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.40 0.40 0.40	
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0	±0.1	±1.0	±1.0	μΑ
I <sub>OZ</sub>	Maximum 3–State Leakage Current	$ \begin{array}{l} \text{Output in High Impedance State} \\ \text{V}_{\text{IN}} = \text{V}_{\text{IL}} \text{ or } \text{V}_{\text{IH}} \\ \text{V}_{\text{OUT}} = \text{V}_{\text{CC}} \text{ or GND} \end{array} $	6.0	±0.5	±5.0	±10.0	μΑ
Icc	Maximum Quiescent Supply Current (per Package)	$V_{IN} = V_{CC} \text{ or } GND$ $I_{OUT} = 0 \ \mu A$	6.0	4	40	160	μΑ

## **AC CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

	Guaranteed Limit		mit			
Symbol	Parameter	v <sub>cc</sub> v	–55 to 25°C	≤85°C	≤125°C	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Input A to Output Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	80 30 18 15	100 40 23 20	120 55 28 25	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Propagation Delay, Output Enable to Output Y (Figures 3 and 5)	2.0 3.0 4.5 6.0	110 45 25 21	140 60 31 26	165 75 38 31	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Propagation Delay, Output Enable to Output Y (Figures 3 and 5)	2.0 3.0 4.5 6.0	110 45 25 21	140 60 31 26	165 75 38 31	ns
t <sub>TLH</sub> , Maximum Output Transition Time, Any Output t <sub>THL</sub> (Figures 2 and 4)		2.0 3.0 4.5 6.0	60 22 12 10	75 28 15 13	90 34 18 15	ns
C <sub>IN</sub>	Maximum Input Capacitance		10	10	10	pF
C <sub>OUT</sub>	Maximum 3-State Output Capacitance (High Impedance State Output)		15	15	15	pF
		Туріса	al @ 25°C, V	/ <sub>CC</sub> = 5.0 V,	V <sub>EE</sub> = 0 V	
C <sub>PD</sub>	Power Dissipation Capacitance (Per Buffer) (Note 7)			35		pF

7. Used to determine the no–load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

















\*Includes all probe and jig capacitance

Figure 5. Test Circuit

## **PIN DESCRIPTIONS**

#### INPUTS

## A1, A2, A3, A4, A5, A6, A7, A8 (PINS 2, 3, 4, 5, 6, 7, 8, 9)

Data input pins. Data on these pins appear in non-inverted form on the corresponding Y outputs, when the outputs are enabled.

#### CONTROLS

#### OE1, OE2 (PINS 1, 19)

Output enables (active-low). When a low voltage is applied to both of these pins, the outputs are enabled and the

device functions as an non-inverting buffer. When a high voltage is applied to either input, the outputs assume the high impedance state.

## OUTPUTS

# Y1, Y2, Y3, Y4, Y5, Y6, Y7, Y8 (PINS 18, 17, 16, 15, 14, 13, 12, 11)

Device outputs. Depending upon the state of the output enable pins, these outputs are either non-inverting outputs or high-impedance outputs.



Figure 6. Logic Detail

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC74HC541ADWG	SOIC-20 WIDE (Pb-Free)	38 Units / Rail
MC74HC541ADWR2G	SOIC-20 WIDE (Pb-Free)	1000 Tape & Reel
NLV74HC541ADWR2G*	SOIC-20 WIDE (Pb-Free)	1000 Tape & Reel
MC74HC541ADTG	TSSOP-20 (Pb-Free)	75 Units / Rail
MC74HC541ADTR2G	TSSOP-20 (Pb-Free)	2500 Tape & Reel
NLV74HC541ADTR2G*	TSSOP-20 (Pb-Free)	2500 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

## PACKAGE DIMENSIONS





 DITES:
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: MILLIMETER.
DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
DIMENSION B DOES NOT INCLUDE INTERI FAD EI ASH OR PROTRUSION INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION, ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE – W-.

	MALE I IN	INC	HES	
	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX
Α	6.40	6.60	0.252	0.260
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	0.65 BSC		BSC
Η	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
Κ	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC			BSC
М	0°	8°	0 °	8°



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SOIC-20 **DW SUFFIX** CASE 751D-05 **ISSUE G** 



NOTES:

- 1. 2.
- DIMENSIONS ARE IN MILLIMETERS. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD 3. PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 PER SIDE. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B 5. DIMENSION AT MAXIMUM MATERIAL CONDITION.

		MILLIMETERS		
0	DIM	MIN	MAX	
	Α	2.35	2.65	
	A1	0.10	0.25	
	В	0.35	0.49	
	C	0.23	0.32	
	D	12.65	12.95	
	Е	7.40	7.60	
	е	1.27	BSC	
	Н	10.05	10.55	
	h	0.25	0.75	
	L	0.50	0.90	
	θ	0 °	7 °	

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